

**ZXMS6005DT8**  
**60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE**  
**INTELLIFET™ MOSFET**

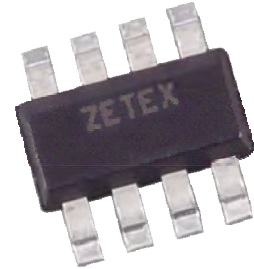
**SUMMARY**

**Continuous drain source voltage 60 V**

**On-state resistance 200 mΩ**

**Nominal load current (V<sub>IN</sub> = 5V) 1.8 A**

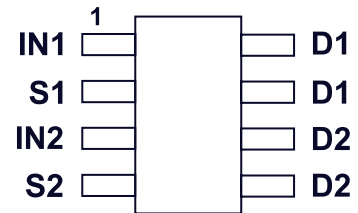
**Clamping Energy 210 mJ**



**SM8 Package**

**DESCRIPTION**

The ZXMS6005DT8 is a dual self protected low side MOSFET with logic level input. It integrates over-temperature, over-current, over-voltage (active clamp) and ESD protected logic level functionality independently per channel. The ZXMS6005DT8 is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.



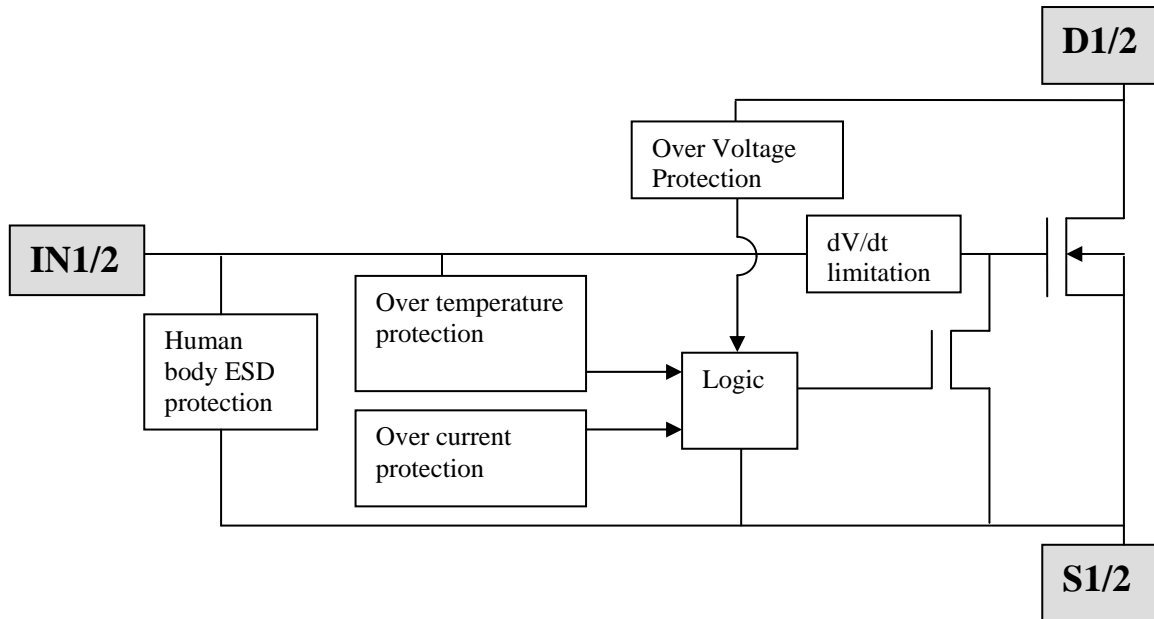
**FEATURES**

- Compact dual package
- Low input current
- Logic Level Input (3.3V and 5V)
- Short circuit protection with auto restart
- Over voltage protection (active clamp)
- Thermal shutdown with auto restart
- Over-current protection
- Input Protection (ESD)
- High continuous current rating

**ORDERING INFORMATION**

DEVICE	PART MARK	REEL SIZE (inches)	TAPE WIDTH (mm)	QUANTITY PER REEL
ZXMS6005DT8TA	ZXMS 6005D	7	12 embossed	1,000 units

## FUNCTIONAL BLOCK DIAGRAM



## APPLICATIONS AND INFORMATION

- Two completely isolated independent channels
- Especially suited for loads with a high in-rush current such as lamps and motors.
- All types of resistive, inductive and capacitive loads in switching applications.
- $\mu\text{C}$  compatible power switch for 12V DC applications.
- Automotive rated.
- Replaces electromechanical relays and discrete circuits.
- Linear Mode capability - the current-limiting protection circuitry is designed to de-activate at low  $V_{\text{DS}}$  to minimise on state power dissipation. The maximum DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry. This does not compromise the product's ability to self-protect at low  $V_{\text{DS}}$ .

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Continuous Drain-Source Voltage	$V_{DS}$	60	V
Drain-Source Voltage for short circuit protection	$V_{DS(SC)}$	24	V
Continuous Input Voltage	$V_{IN}$	-0.5 ... +6	V
Continuous Input Current -0.2V ≤ $V_{IN}$ ≤ 6V $V_{IN}$ < -0.2V or $V_{IN}$ > 6V	$I_{IN}$	No limit $ I_{IN}  \leq 2$	mA
Operating Temperature Range	$T_j$	-40 to +150	°C
Storage Temperature Range	$T_{stg}$	-55 to +150	°C
Power Dissipation at $T_A = 25^\circ\text{C}$ (a)(d) Linear Derating Factor	$P_D$	1.16 9.28	W mW/°C
Power Dissipation at $T_A = 25^\circ\text{C}$ (a)(e) Linear Derating Factor	$P_D$	1.67 13.3	W mW/°C
Power Dissipation at $T_A = 25^\circ\text{C}$ (b)(d) Linear Derating Factor	$P_D$	2.13 17	W mW/°C
Pulsed Drain Current @ $V_{IN}=3.3\text{V}$	$I_{DM}$	5	A
Pulsed Drain Current @ $V_{IN}=5\text{V}$	$I_{DM}$	6	A
Continuous Source Current (Body Diode) (a)	$I_S$	2.5	A
Pulsed Source Current (Body Diode)	$I_{SM}$	10	A
Unclamped single pulse inductive energy, $T_j=25^\circ\text{C}$ , $I_D=0.5\text{A}$ , $V_{DD}=24\text{V}$	$E_{AS}$	210	mJ
Electrostatic Discharge (Human Body Model)	$V_{ESD}$	4000	V
Charged Device Model	$V_{CDM}$	1000	V

### THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to Ambient (a)(d)	$R_{\theta JA}$	108	°C/W
Junction to Ambient (a)(e)	$R_{\theta JA}$	75	°C/W
Junction to Ambient (b)(d)	$R_{\theta JA}$	58.7	°C/W
Junction to Case (f)	$R_{\theta JC}$	26.5	°C/W

### NOTES

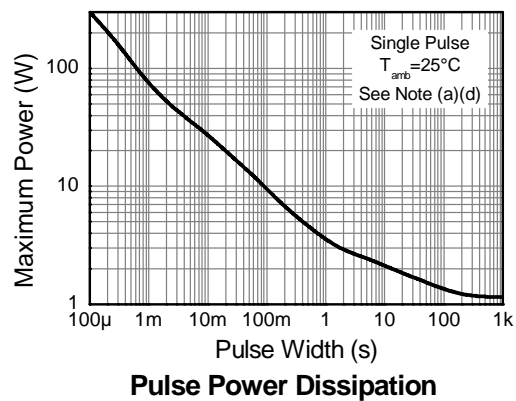
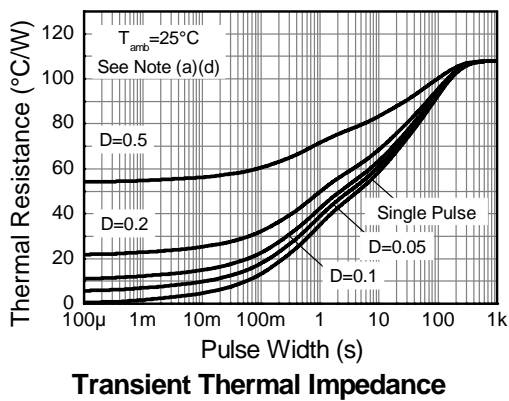
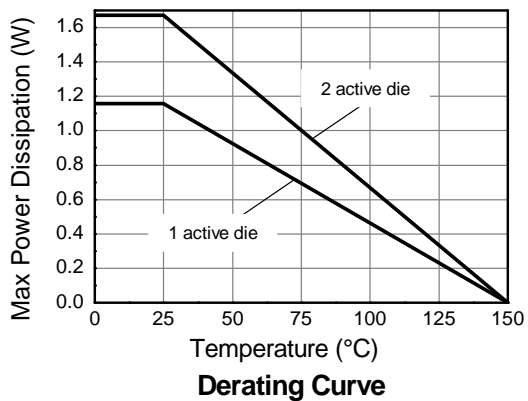
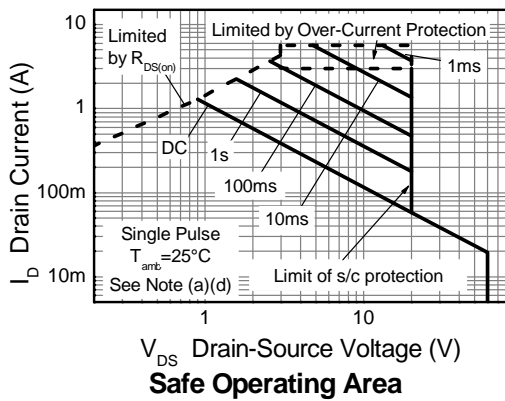
- For a dual device surface mounted on a 25mm x 25mm single sided 1oz weight copper split down the middle on 1.6mm FR4 board, in still air conditions.
- For a dual device surface mounted on FR4 PCB measured at  $t \leq 10\text{sec}$
- Repetitive rating 25mm x 25mm FR4 PCB,  $D=0.02$ , Pulse width=300 $\mu\text{s}$  – pulse width limited by junction temperature. Refer to transient thermal impedance graph.
- For a dual device with one active die.
- For a dual device with 2 active die running at equal power.
- Thermal resistance from junction to the mounting surface of the drain pin.

## RECOMMENDED OPERATING CONDITIONS

The ZXMS6005DT8 is optimised for use with  $\mu\text{C}$  operating from 3.3V and 5V supplies.

Symbol	Description	Min	Max	Units
$V_{IN}$	Input voltage range	0	5.5	V
$T_A$	Ambient temperature range	-40	125	$^{\circ}\text{C}$
$V_{IH}$	High level input voltage for MOSFET to be on	3	5.5	V
$V_{IL}$	Low level input voltage for MOSFET to be off	0	0.7	V
$V_P$	Peripheral supply voltage (voltage to which load is referred)	0	24	V

## CHARACTERISTICS



**ELECTRICAL CHARACTERISTICS (at  $T_{amb} = 25^{\circ}\text{C}$  unless otherwise stated).**

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	CONDITIONS
<b>Static Characteristics</b>						
Drain-Source Clamp Voltage	$V_{DS(AZ)}$	60	65	70	V	$I_D=10\text{mA}$
Off state Drain Current	$I_{DSS}$			1	$\mu\text{A}$	$V_{DS}=12\text{V}, V_{IN}=0\text{V}$
Off state Drain Current	$I_{DSS}$			2	$\mu\text{A}$	$V_{DS}=36\text{V}, V_{IN}=0\text{V}$
Input Threshold Voltage	$V_{IN(th)}$	0.7	1	1.5	V	$V_{DS}=V_{GS}, I_D=1\text{mA}$
Input Current	$I_{IN}$		60	100	$\mu\text{A}$	$V_{IN}=+3\text{V}$
Input Current	$I_{IN}$		120	200	$\mu\text{A}$	$V_{IN}=+5\text{V}$
Input Current while over temperature active				300	$\mu\text{A}$	$V_{IN}=+5\text{V}$
Static Drain-Source On-State Resistance	$R_{DS(on)}$		170	250	$\text{m}\Omega$	$V_{IN}=+3\text{V}, I_D=1\text{A}$
Static Drain-Source On-State Resistance	$R_{DS(on)}$		150	200	$\text{m}\Omega$	$V_{IN}=+5\text{V}, I_D=1\text{A}$
Continuous Drain Current (a)(e)	$I_D$	1.4			A	$V_{IN}=3\text{V}; T_A=25^{\circ}\text{C}$
Continuous Drain Current (a)(e)	$I_D$	1.6			A	$V_{IN}=5\text{V}; T_A=25^{\circ}\text{C}$
Continuous Drain Current (a)(d)	$I_D$	1.7			A	$V_{IN}=3\text{V}; T_A=25^{\circ}\text{C}$
Continuous Drain Current (a)(d)	$I_D$	1.8			A	$V_{IN}=5\text{V}; T_A=25^{\circ}\text{C}$
Current Limit (g)	$I_{D(LIM)}$	2.2	5		A	$V_{IN}=+3\text{V},$
Current Limit (g)	$I_{D(LIM)}$	3.3	7		A	$V_{IN}=+5\text{V}$
<b>Dynamic Characteristics</b>						
Turn On Delay Time	$t_{d(on)}$		6		$\mu\text{s}$	$V_{DD}=12\text{V}, I_D=1\text{A}, V_{GS}=5\text{V}$
Rise time	$t_r$		14		$\mu\text{s}$	
Turn Off Delay Time	$t_{d(off)}$		34		$\mu\text{s}$	
Fall Time	$f_f$		19		$\mu\text{s}$	

Notes:

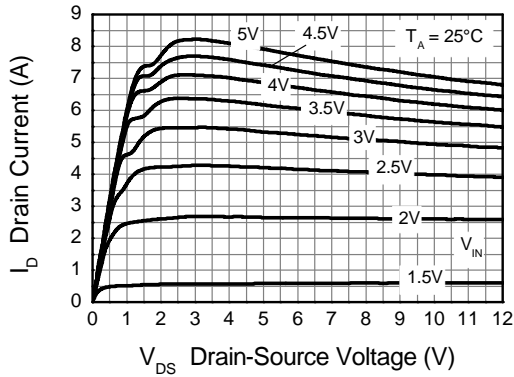
- (g) The drain current is restricted only when the device is in saturation (see graph 'typical output characteristic'). This allows the device to be used in the fully on state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	CONDITIONS
<b>Over-temperature Protection</b>						
Thermal Overload Trip Temperature (h)	T <sub>JT</sub>	150	175		°C	
Thermal hysteresis (h)			10		°C	

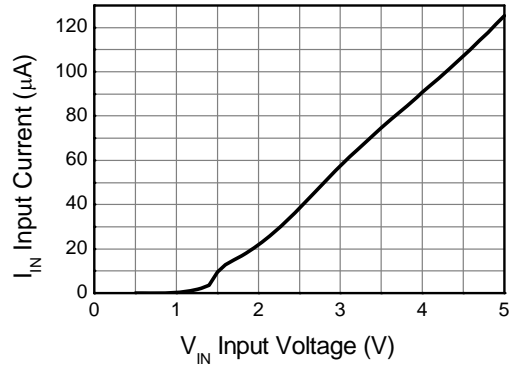
Note:

- (h) Over-temperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as “outside” normal operating range, so this part is not designed to withstand over-temperature for extended periods..

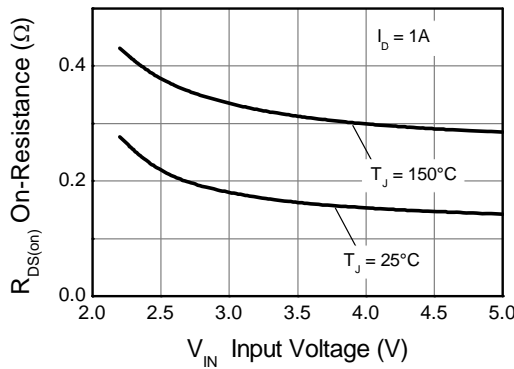
**TYPICAL CHARACTERISTICS**



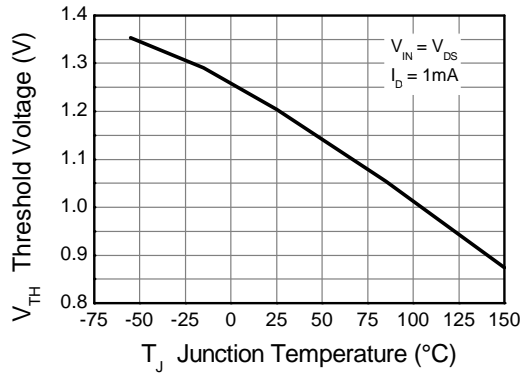
**Typical Output Characteristic**



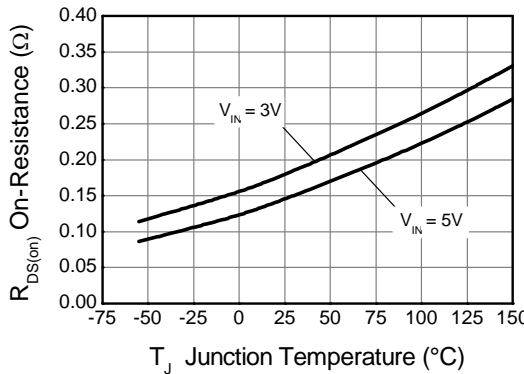
**Input Current vs Input Voltage**



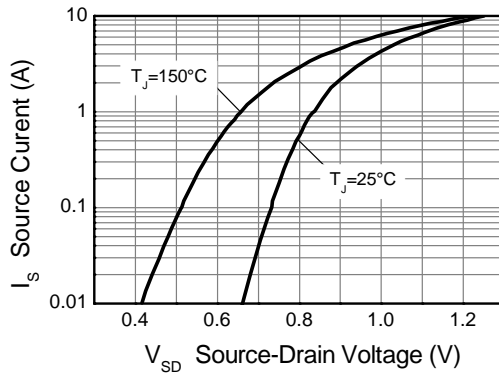
**On-Resistance vs Input Voltage**



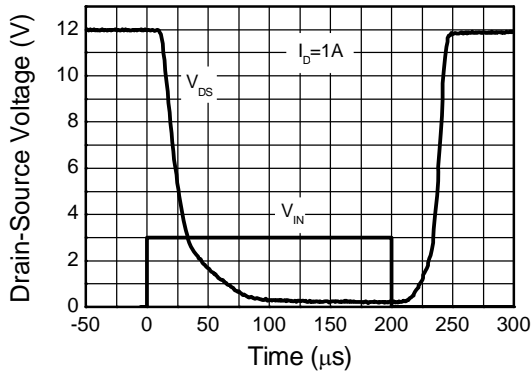
**Threshold Voltage vs Temperature**



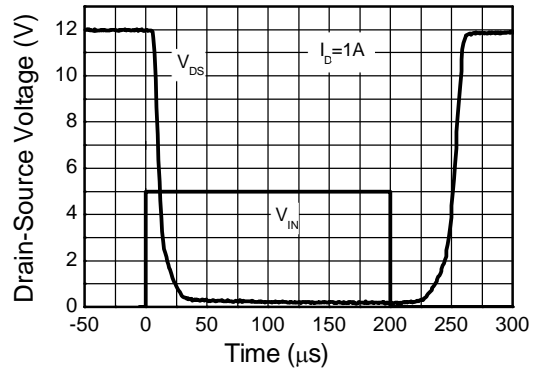
**On-Resistance vs Temperature**



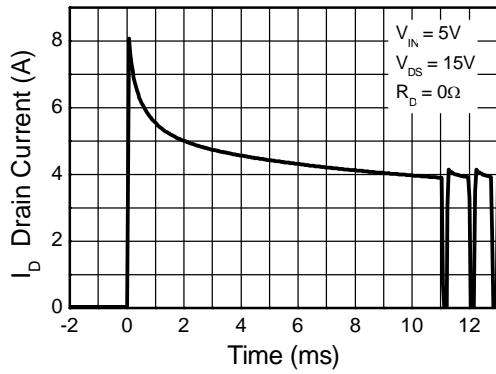
**Reverse Diode Characteristic**



**Switching Speed**



**Switching Speed**



**Typical Short Circuit Protection**



**IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDING TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

**LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or

2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2010, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.